

SiGe High-Linearity, 815MHz to 995MHz Downconversion Mixer with LO Buffer/Switch

General Description

The MAX9986 high-linearity downconversion mixer provides 10dB gain, +23.6dBm IIP3, and 9.3dB NF for 815MHz to 995MHz base-station receiver applications. With a 960MHz to 1180MHz LO frequency range, this particular mixer is ideal for high-side LO injection receiver architectures. Low-side LO injection is supported by the MAX9984, which is pin-for-pin and functionally compatible with the MAX9986.

In addition to offering excellent linearity and noise performance, the MAX9986 also yields a high level of component integration. This device includes a double-balanced passive mixer core, an IF amplifier, a dual-input LO selectable switch, and an LO buffer. On-chip baluns are also integrated to allow for single-ended RF and LO inputs. The MAX9986 requires a nominal LO drive of 0dBm, and supply current is guaranteed to be below 265mA.

The MAX9984/MAX9986 are pin compatible with the MAX9994/MAX9996 1700MHz to 2200MHz mixers, making this entire family of downconverters ideal for applications where a common PC board layout is used for both frequency bands. The MAX9986 is also functionally compatible with the MAX9993.

The MAX9986 is available in a compact, 20-pin, thin QFN package (5mm x 5mm) with an exposed paddle. Electrical performance is guaranteed over the extended -40°C to +85°C temperature range.

Applications

850MHz W-CDMA Base Stations
GSM 850/GSM 900 2G and 2.5G EDGE Base Stations
cdmaOne™ and cdma2000® Base Stations
iDEN® Base Stations
Predistortion Receivers
Fixed Broadband Wireless Access
Wireless Local Loop
Private Mobile Radios
Military Systems
Microwave Links
Digital and Spread-Spectrum Communication Systems

cdma2000 is a registered trademark of the Telecommunications Industry Association.
cdmaOne is a trademark of CDMA Development Group.
iDEN is a registered trademark of Motorola, Inc.

Features

- ◆ 815MHz to 995MHz RF Frequency Range
- ◆ 960MHz to 1180MHz LO Frequency Range (MAX9986)
- ◆ 570MHz to 850MHz LO Frequency Range (MAX9984)
- ◆ 50MHz to 250MHz IF Frequency Range
- ◆ 10dB Conversion Gain
- ◆ +23.6dBm Input IP3
- ◆ +12dBm Input 1dB Compression Point
- ◆ 9.3dB Noise Figure
- ◆ 67dBc 2LO-2RF Spurious Rejection at PRF = -10dBm
- ◆ Integrated LO Buffer
- ◆ Integrated RF and LO Baluns for Single-Ended Inputs
- ◆ Low -3dBm to +3dBm LO Drive
- ◆ Built-In SPDT LO Switch with 49dB LO1 to LO2 Isolation and 50ns Switching Time
- ◆ Pin Compatible with MAX9994/MAX9996 1700MHz to 2200MHz Mixers
- ◆ Functionally Compatible with MAX9993
- ◆ External Current-Setting Resistors Provide Option for Operating Mixer in Reduced Power/Reduced Performance Mode
- ◆ Lead-Free Package Available

Ordering Information

PART	TEMP RANGE	PIN-PACKAGE	PKG CODE
MAX9986ETP	-40°C to +85°C	20 Thin QFN-EP* 5mm x 5mm	T2055-3
MAX9986ETP-T	-40°C to +85°C	20 Thin QFN-EP* 5mm x 5mm	T2055-3
MAX9986ETP+D	-40°C to +85°C	20 Thin QFN-EP* 5mm x 5mm	T2055-3
MAX9986ETP+TD	-40°C to +85°C	20 Thin QFN-EP* 5mm x 5mm	T2055-3

*EP = Exposed paddle.

+ = Lead free. D = Dry pack. T = Tape-and-reel.

Pin Configuration/Functional Diagram and Typical Application Circuit appear at end of data sheet.

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ABSOLUTE MAXIMUM RATINGS

V _{CC} to GND	-0.3V to +5.5V
IF+, IF-, LOBIAS, LOSEL, IFBIAS to GND.....	-0.3V to (V _{CC} + 0.3V)
TAP	-0.3V to +1.4V
LO1, LO2, LEXT to GND.....	-0.3V to +0.3V
RF, LO1, LO2 Input Power	+12dBm
RF (RF is DC shorted to GND through a balun)50mA
Continuous Power Dissipation (T _A = +70°C) 20-Pin Thin QFN-EP (derate 26.3mW/°C above +70°C).....	2.1W

θ _{JA}	+38°C/W
θ _{JC}	+13°C/W
Operating Temperature Range (Note A)	T _C = -40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (soldering, 10s).....	+300°C

Note A: T_C is the temperature on the exposed paddle of the package.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

(MAX9986 Typical Application Circuit, V_{CC} = +4.75V to +5.25V, no RF signal applied, IF+ and IF- outputs pulled up to V_{CC} through inductive chokes, R₁ = 953Ω, R₂ = 619Ω, T_C = -40°C to +85°C, unless otherwise noted. Typical values are at V_{CC} = +5V, T_C = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Voltage	V _{CC}		4.75	5.00	5.25	V
Supply Current	I _{CC}			222	265	mA
LO_SEL Input-Logic Low	V _{IL}				0.8	V
LO_SEL Input-Logic High	V _{IH}		2			V

AC ELECTRICAL CHARACTERISTICS

(MAX9986 Typical Application Circuit, V_{CC} = +4.75V to +5.25V, RF and LO ports are driven from 50Ω sources, P_{LO} = -3dBm to +3dBm, P_{RF} = -5dBm, f_{RF} = 815MHz to 995MHz, f_{LO} = 960MHz to 1180MHz, f_{IF} = 160MHz, f_{LO} > f_{RF}, T_C = -40°C to +85°C, unless otherwise noted. Typical values are at V_{CC} = +5V, P_{RF} = -5dBm, P_{LO} = 0dBm, f_{RF} = 910MHz, f_{LO} = 1070MHz, f_{IF} = 160MHz, T_C = +25°C, unless otherwise noted.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
RF Frequency Range	f _{RF}	(Note 2)	815		995	MHz
LO Frequency Range	f _{LO}	(Note 2)	960		1180	MHz
		MAX9984	570		850	
IF Frequency Range	f _{IF}	(Note 2)	50		250	MHz
Conversion Gain	G _C	T _C = +25°C	9	10	11	dB
Gain Variation Over Temperature		T _C = -40°C to +85°C		-0.007		dB/°C
Conversion Gain Flatness		Flatness over any one of three frequency bands: f _{RF} = 824MHz to 849MHz f _{RF} = 869MHz to 894MHz f _{RF} = 880MHz to 915MHz		±0.15		dB
Input Compression Point	P _{1dB}	(Note 3)		12		dBm
Input Third-Order Intercept Point	IIP ₃	Two tones: f _{RF1} = 910MHz, f _{RF2} = 911MHz, P _{RF} = -5dBm/tone, f _{LO} = 1070MHz, P _{LO} = 0dBm, T _A = +25°C	21	23.6		dBm
Input IP3 Variation Over Temperature		T _C = +25°C to -40°C		-1.7		dB
		T _C = +25°C to +85°C		+1.0		

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AC ELECTRICAL CHARACTERISTICS (continued)

(MAX9986 *Typical Application Circuit*, $V_{CC} = +4.75V$ to $+5.25V$, RF and LO ports are driven from 50Ω sources, $P_{LO} = -3dBm$ to $+3dBm$, $P_{RF} = -5dBm$, $f_{RF} = 815MHz$ to $995MHz$, $f_{LO} = 960MHz$ to $1180MHz$, $f_{IF} = 160MHz$, $f_{LO} > f_{RF}$, $T_C = -40^\circ C$ to $+85^\circ C$, unless otherwise noted. Typical values are at $V_{CC} = +5V$, $P_{RF} = -5dBm$, $P_{LO} = 0dBm$, $f_{RF} = 910MHz$, $f_{LO} = 1070MHz$, $f_{IF} = 160MHz$, $T_C = +25^\circ C$, unless otherwise noted.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Noise Figure	NF	Single sideband, $f_{IF} = 190MHz$			9.3		dB
Noise Figure Under-Blocking		$f_{RF} = 900MHz$ (no signal) $f_{LO} = 1090MHz$ $f_{BLOCKER} = 990MHz$ $f_{IF} = 190MHz$ (Note 4)	$P_{BLOCKER} = +8dBm$		19		dB
			$P_{BLOCKER} = +11dBm$		24		
Small-Signal Compression Under-Blocking Condition		$P_{FUNDAMENTAL} = -5dBm$ $f_{FUNDAMENTAL} = 910MHz$ $f_{BLOCKER} = 911MHz$	$P_{BLOCKER} = +8dBm$		0.3		dB
			$P_{BLOCKER} = +11dBm$		2		
LO Drive				-3		+3	dBm
Spurious Response at IF	2 x 2	2LO-2RF	$P_{RF} = -10dBm$		67		dBc
			$P_{RF} = -5dBm$		62		
	3 x 3	3LO-3RF	$P_{RF} = -10dBm$		87		
			$P_{RF} = -5dBm$		77		
LO1 to LO2 Isolation		$P_{LO} = +3dBm$ $T_C = +25^\circ C$ (Note 5)	LO2 selected	42	49		dB
			LO1 selected	42	50		
LO Leakage at RF Port		$P_{LO} = +3dBm$			-47		dBm
LO Leakage at IF Port		$P_{LO} = +3dBm$			-30		dBm
RF-to-IF Isolation					46		dB
LO Switching Time		50% of LOSEL to IF settled to within 2°			50		ns
RF Port Return Loss					20		dB
LO Port Return Loss		LO1/2 port selected, LO2/1 and IF terminated			27		dB
		LO1/2 port unselected, LO2/1 and IF terminated			26		
IF Port Return Loss		LO driven at $0dBm$, RF terminated into 50Ω , differential 200Ω			22		dB

Note 1: All limits include external component losses. Output measurements taken at IF output of the *Typical Application Circuit*.

Note 2: Operation outside this range is possible, but with degraded performance of some parameters.

Note 3: Compression point characterized. It is advisable not to operate continuously the mixer RF input above $+12dBm$.

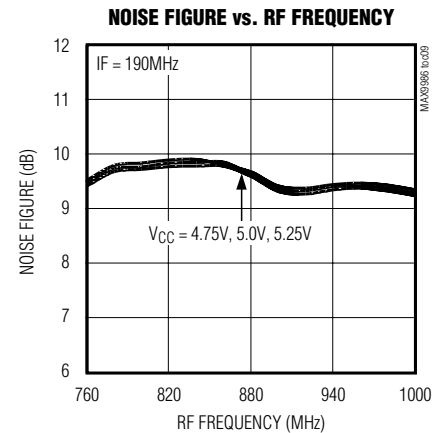
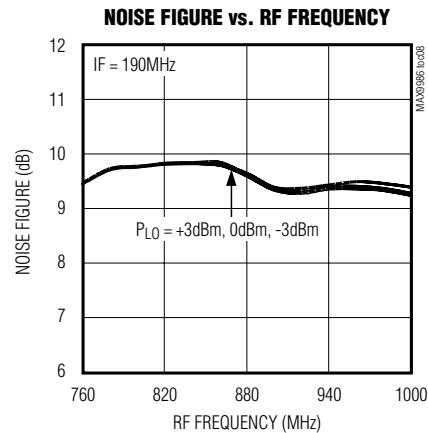
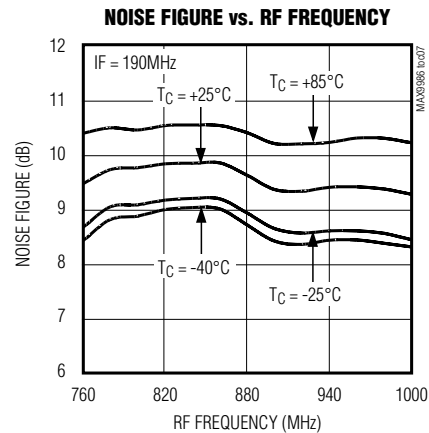
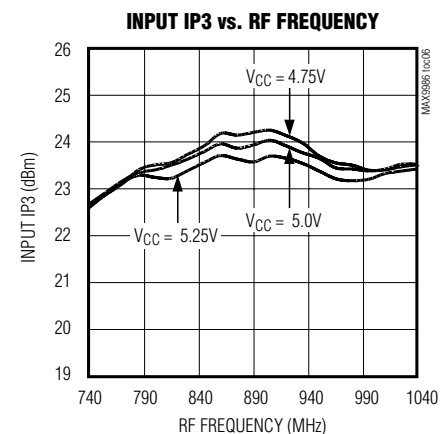
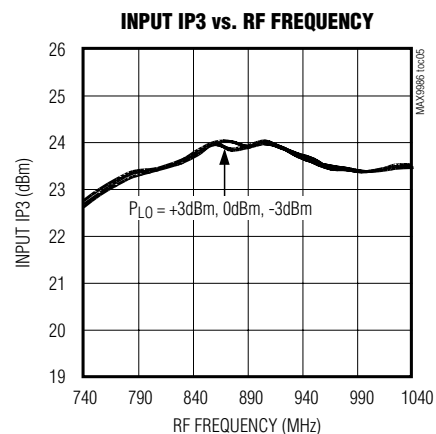
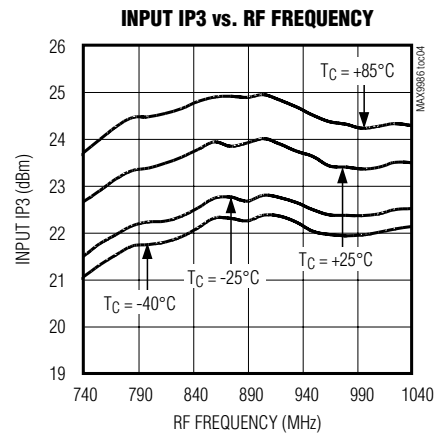
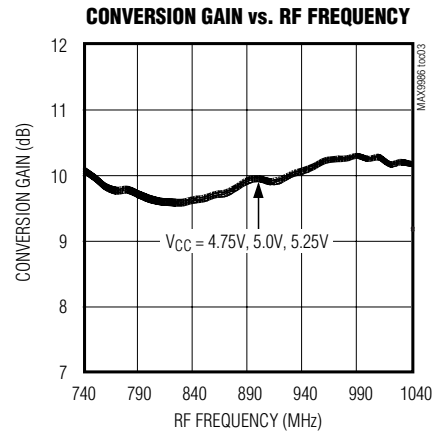
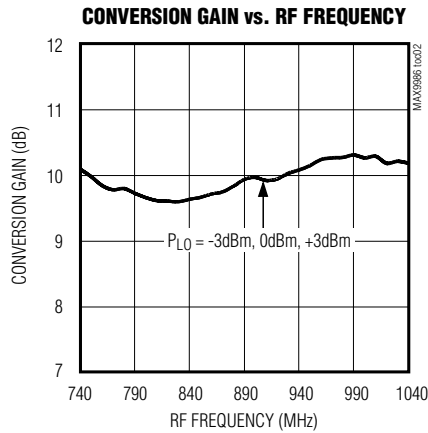
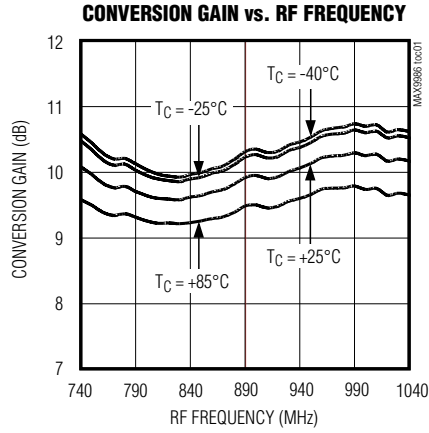
Note 4: Measured with external LO source noise filtered so the noise floor is $-174dBm/Hz$. This specification reflects the effects of all SNR degradations in the mixer, including the LO noise as defined in Maxim Application Note 2021.

Note 5: Guaranteed by design and characterization.

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Typical Operating Characteristics

(MAX9986 Typical Application Circuit, $V_{CC} = +5.0V$, $P_{LO} = 0dBm$, $P_{RF} = -5dBm$, $f_{LO} > f_{RF}$, $f_{IF} = 160MHz$, unless otherwise noted.)

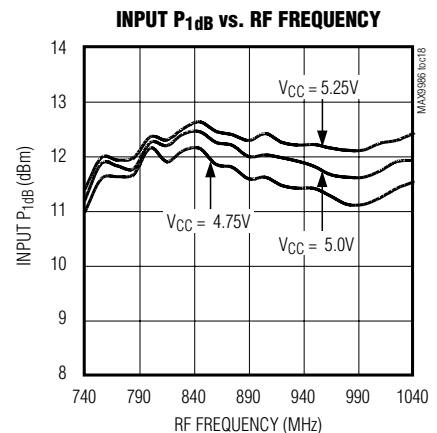
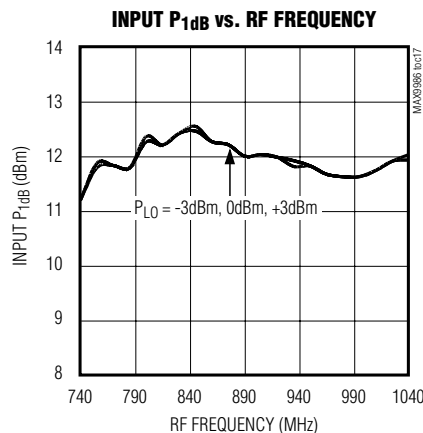
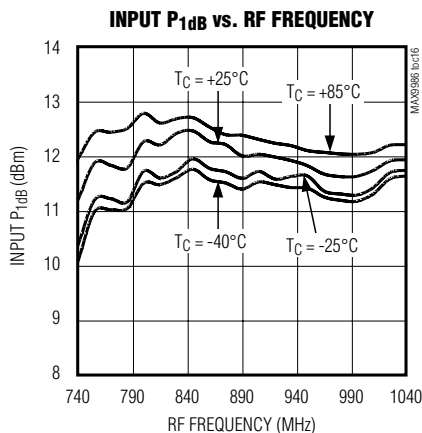
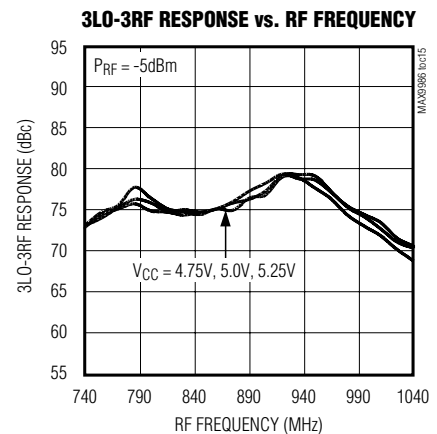
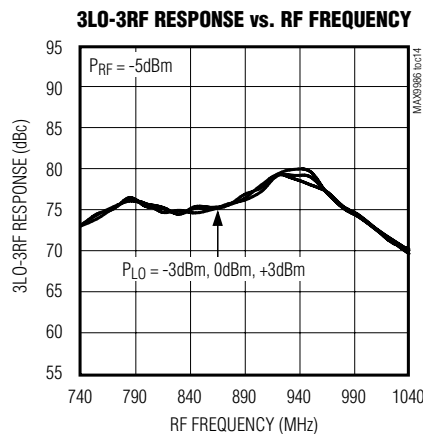
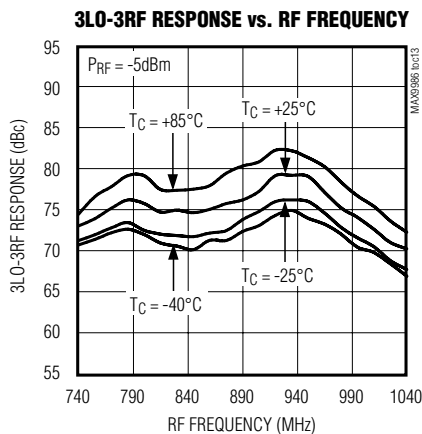
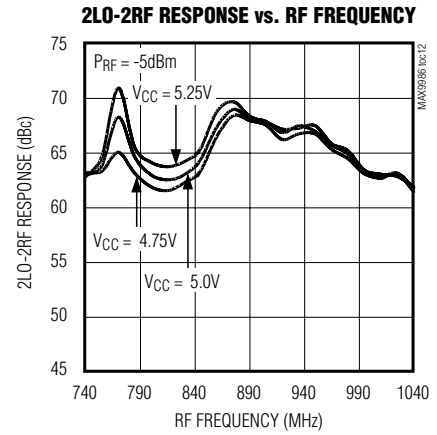
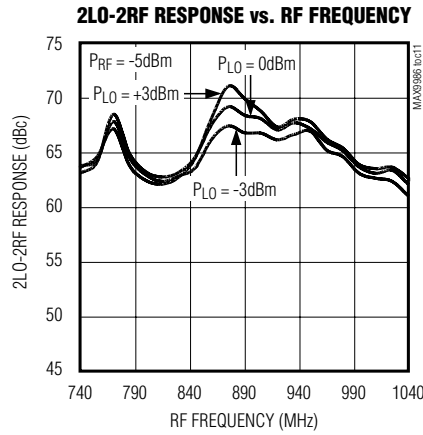
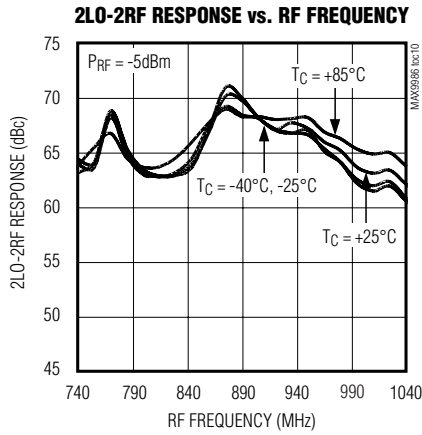


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Typical Operating Characteristics (continued)

(MAX9986 Typical Application Circuit, $V_{CC} = +5.0V$, $P_{LO} = 0dBm$, $P_{RF} = -5dBm$, $f_{LO} > f_{RF}$, $f_{IF} = 160MHz$, unless otherwise noted.)

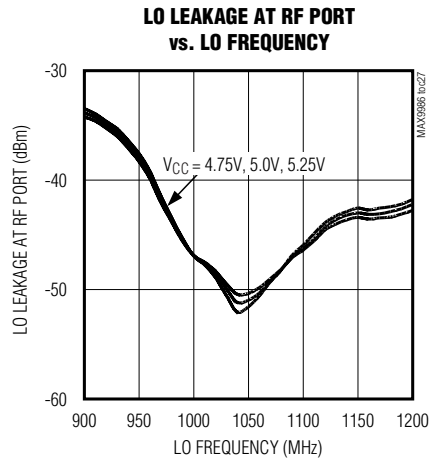
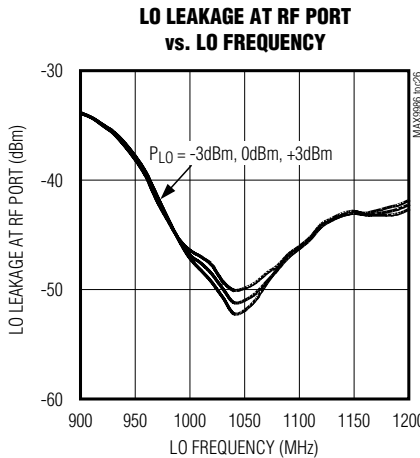
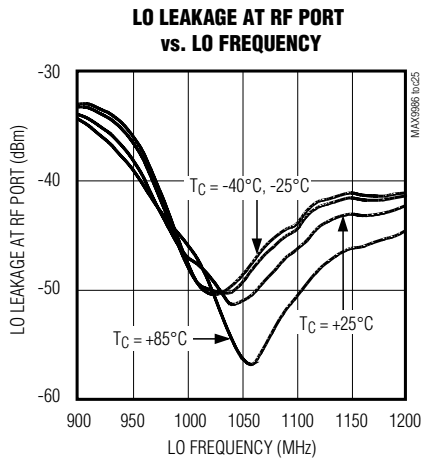
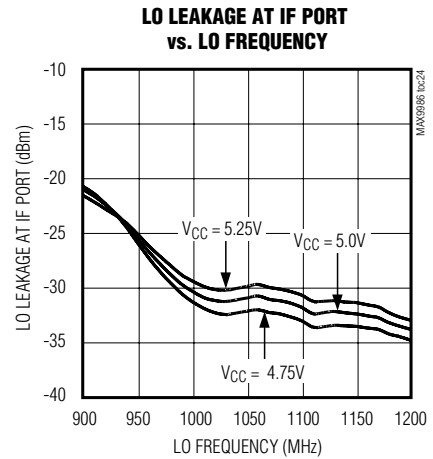
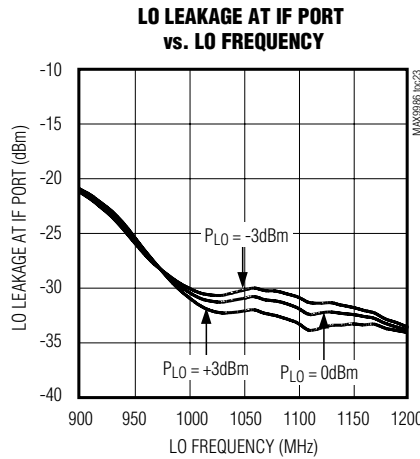
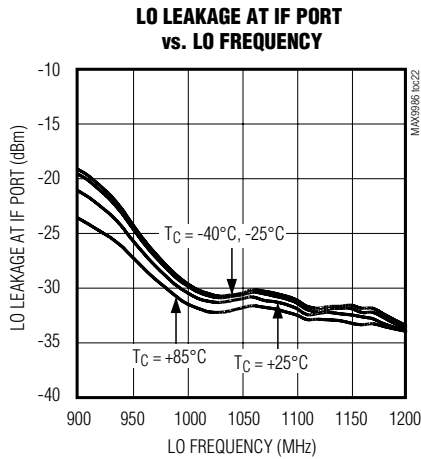
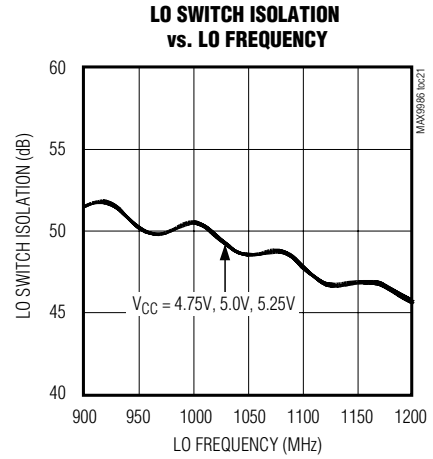
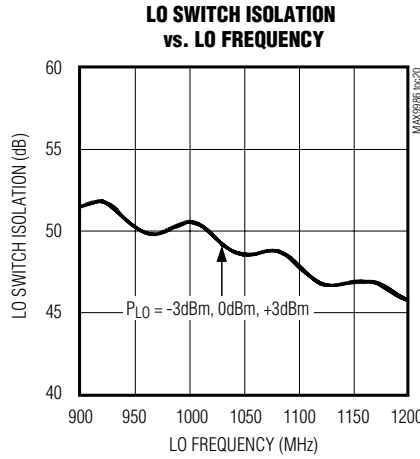
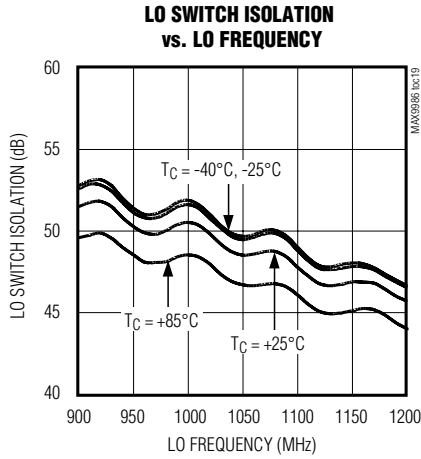
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SiGe High-Linearity, 815MHz to 995MHz Downconversion Mixer with LO Buffer/Switch

Typical Operating Characteristics (continued)

(MAX9986 Typical Application Circuit, $V_{CC} = +5.0V$, $P_{LO} = 0dBm$, $P_{RF} = -5dBm$, $f_{LO} > f_{RF}$, $f_{IF} = 160MHz$, unless otherwise noted.)

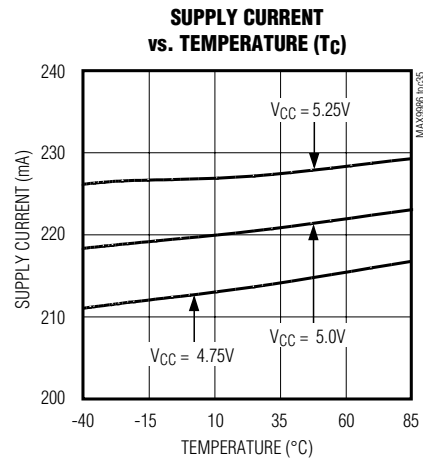
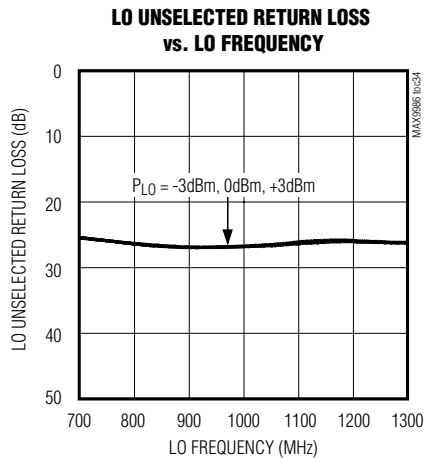
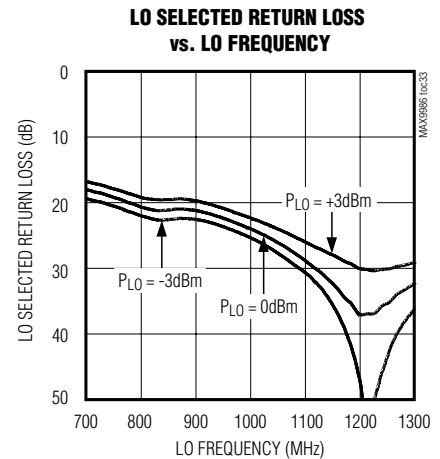
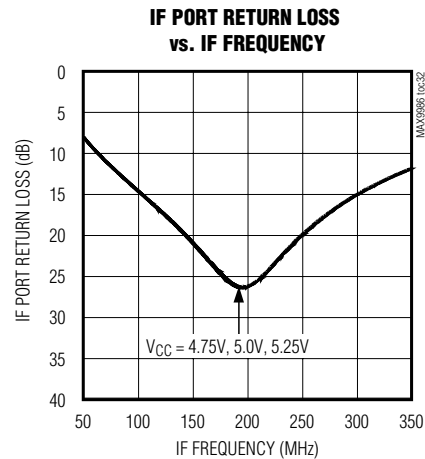
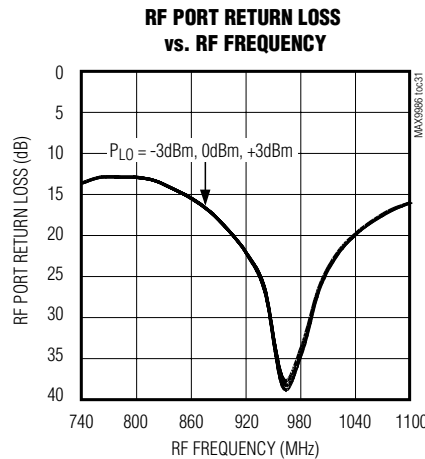
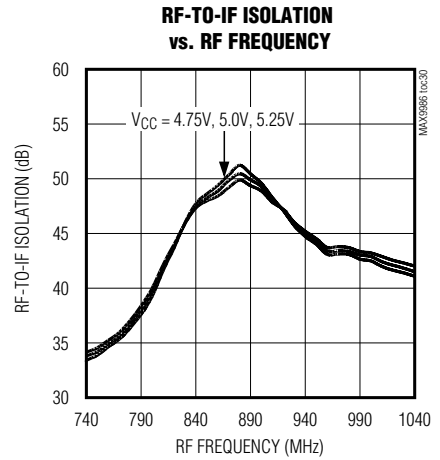
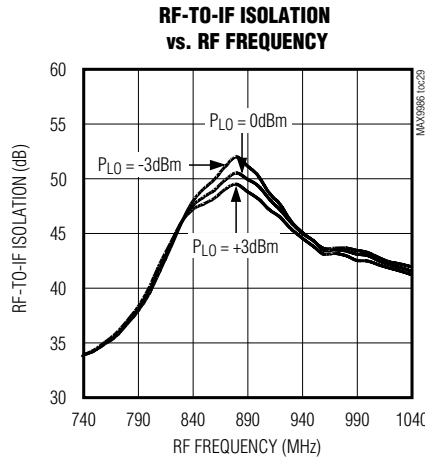
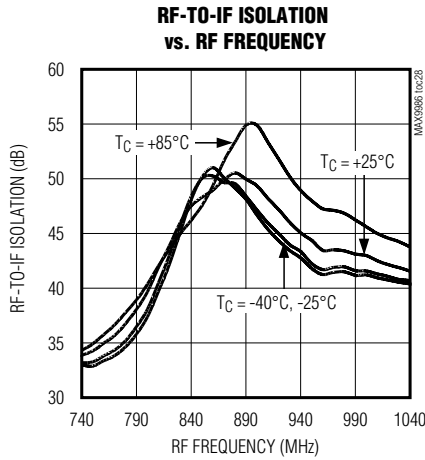


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Typical Operating Characteristics (continued)

(MAX9986 Typical Application Circuit, $V_{CC} = +5.0V$, $P_{LO} = 0dBm$, $P_{RF} = -5dBm$, $f_{LO} > f_{RF}$, $f_{IF} = 160MHz$, unless otherwise noted.)

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Pin Description

PIN	NAME	FUNCTION
1, 6, 8, 14	VCC	Power-Supply Connection. Bypass each VCC pin to GND with capacitors as shown in the <i>Typical Application Circuit</i> .
2	RF	Single-Ended 50Ω RF Input. This port is internally matched and DC shorted to GND through a balun. Requires an external DC-blocking capacitor.
3	TAP	Center Tap of the Internal RF Balun. Bypass to GND with capacitors close to the IC, as shown in the <i>Typical Application Circuit</i> .
4, 5, 10, 12, 13, 17	GND	Ground
7	LOBIAS	Bias Resistor for Internal LO Buffer. Connect a 619Ω ±1% resistor from LOBIAS to the power supply.
9	LOSEL	Local Oscillator Select. Logic control input for selecting LO1 or LO2.
11	LO1	Local Oscillator Input 1. Drive LOSEL low to select LO1.
15	LO2	Local Oscillator Input 2. Drive LOSEL high to select LO2.
16	LEXT	External Inductor Connection. Connect a low-ESR, 30nH inductor from LEXT to GND. This inductor carries approximately 140mA DC current.
18, 19	IF-, IF+	Differential IF Outputs. Each output requires external bias to VCC through an RF choke (see the <i>Typical Application Circuit</i>).
20	IFBIAS	IF Bias Resistor Connection for IF Amplifier. Connect a 953Ω ±1% resistor from IFBIAS to GND.
EP	GND	Exposed Ground Paddle. Solder the exposed paddle to the ground plane using multiple vias.

Detailed Description

The MAX9986 high-linearity downconversion mixer provides 10dB of conversion gain and +23.6dBm of IIP3, with a typical 9.3dB noise figure. The integrated baluns and matching circuitry allow for 50Ω single-ended interfaces to the RF and the two LO ports. A single-pole, double-throw (SPDT) switch provides 50ns switching time between the two LO inputs with 49dB of LO-to-LO isolation. Furthermore, the integrated LO buffer provides a high drive level to the mixer core, reducing the LO drive required at the MAX9986's inputs to a -3dBm to +3dBm range. The IF port incorporates a differential output, which is ideal for providing enhanced IIP2 performance.

Specifications are guaranteed over broad frequency ranges to allow for use in cellular band GSM, cdma2000, iDEN, and W-CDMA 2G/2.5G/3G base stations. The MAX9986 is specified to operate over a 815MHz to 995MHz RF frequency range, a 960MHz to 1180MHz LO frequency range, and a 50MHz to 250MHz IF frequency range. Operation beyond these ranges is possible; see the *Typical Operating Characteristics* for additional details.

RF Input and Balun

The MAX9986 RF input is internally matched to 50Ω, requiring no external matching components. A DC-blocking capacitor is required because the input is internally DC shorted to ground through the on-chip balun.

LO Inputs, Buffer, and Balun

The MAX9986 is ideally suited for high-side LO injection applications with a 960MHz to 1180MHz LO frequency range. For a device with a 570MHz to 850MHz LO frequency range, refer to the MAX9984 data sheet. As an added feature, the MAX9986 includes an internal LO SPDT switch that can be used for frequency-hopping applications. The switch selects one of the two single-ended LO ports, allowing the external oscillator to settle on a particular frequency before it is switched in. LO switching time is typically less than 50ns, which is more than adequate for virtually all GSM applications. If frequency hopping is not employed, set the switch to either of the LO inputs. The switch is controlled by a digital input (LOSEL): logic-high selects LO2, logic-low selects LO1. To avoid damage to the part, voltage must be applied to VCC before digital logic is applied to LOSEL. LO1 and LO2 inputs are internally matched to 50Ω, requiring only a 82pF DC-blocking capacitor.

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A two-stage internal LO buffer allows a wide input power range for the LO drive. All guaranteed specifications are for an LO signal power from -3dBm to +3dBm. The on-chip low-loss balun, along with an LO buffer, drives the double-balanced mixer. All interfacing and matching components from the LO inputs to the IF outputs are integrated on-chip.

High-Linearity Mixer

The core of the MAX9986 is a double-balanced, high-performance passive mixer. Exceptional linearity is provided by the large LO swing from the on-chip LO buffer. When combined with the integrated IF amplifiers, the cascaded IIP3, 2LO-2RF rejection, and NF performance is typically 23.6dBm, 67dBc, and 9.3dB, respectively.

Differential IF Output Amplifier

The MAX9986 mixer has a 50MHz to 250MHz IF frequency range. The differential, open-collector IF output ports require external pullup inductors to V_{CC} . Note that these differential outputs are ideal for providing enhanced 2LO-2RF rejection performance. Single-ended IF applications require a 4:1 balun to transform the 200 Ω differential output impedance to a 50 Ω single-ended output.

Applications Information

Input and Output Matching

The RF and LO inputs are internally matched to 50 Ω . No matching components are required. RF and LO inputs require only DC-blocking capacitors for interfacing.

The IF output impedance is 200 Ω (differential). For evaluation, an external low-loss 4:1 (impedance ratio) balun transforms this impedance down to a 50 Ω single-ended output (see the *Typical Application Circuit*).

Bias Resistors

Bias currents for the LO buffer and the IF amplifier are optimized by fine tuning resistors R1 and R2. If reduced current is required at the expense of performance, contact the factory for details. If the $\pm 1\%$ bias resistor values are not readily available, substitute standard $\pm 5\%$ values.

LEXT Inductor

LEXT serves to improve the LO-to-IF and RF-to-IF leakage. The inductance value can be adjusted by the user to

optimize the performance for a particular frequency band. Since approximately 140mA flows through this inductor, it is important to use a low-DCR wire-wound coil.

If the LO-to-IF and RF-to-IF leakage are not critical parameters, the inductor can be replaced by a short circuit to ground.

Layout Considerations

A properly designed PC board is an essential part of any RF/microwave circuit. Keep RF signal lines as short as possible to reduce losses, radiation, and inductance. For the best performance, route the ground pin traces directly to the exposed pad under the package. The PC board exposed pad **MUST** be connected to the ground plane of the PC board. It is suggested that multiple vias be used to connect this pad to the lower level ground planes. This method provides a good RF/thermal conduction path for the device. Solder the exposed pad on the bottom of the device package to the PC board. The MAX9986 Evaluation Kit can be used as a reference for board layout. Gerber files are available upon request at www.maxim-ic.com.

Power-Supply Bypassing

Proper voltage-supply bypassing is essential for high-frequency circuit stability. Bypass each V_{CC} pin and TAP with the capacitors shown in the *Typical Application Circuit*; see Table 1. Place the TAP bypass capacitor to ground within 100 mils of the TAP pin.

Exposed Pad RF/Thermal Considerations

The exposed paddle (EP) of the MAX9986's 20-pin thin QFN-EP package provides a low thermal-resistance path to the die. It is important that the PC board on which the MAX9986 is mounted be designed to conduct heat from the EP. In addition, provide the EP with a low-inductance path to electrical ground. The EP **MUST** be soldered to a ground plane on the PC board, either directly or through an array of plated via holes.

Chip Information

TRANSISTOR COUNT: 1017

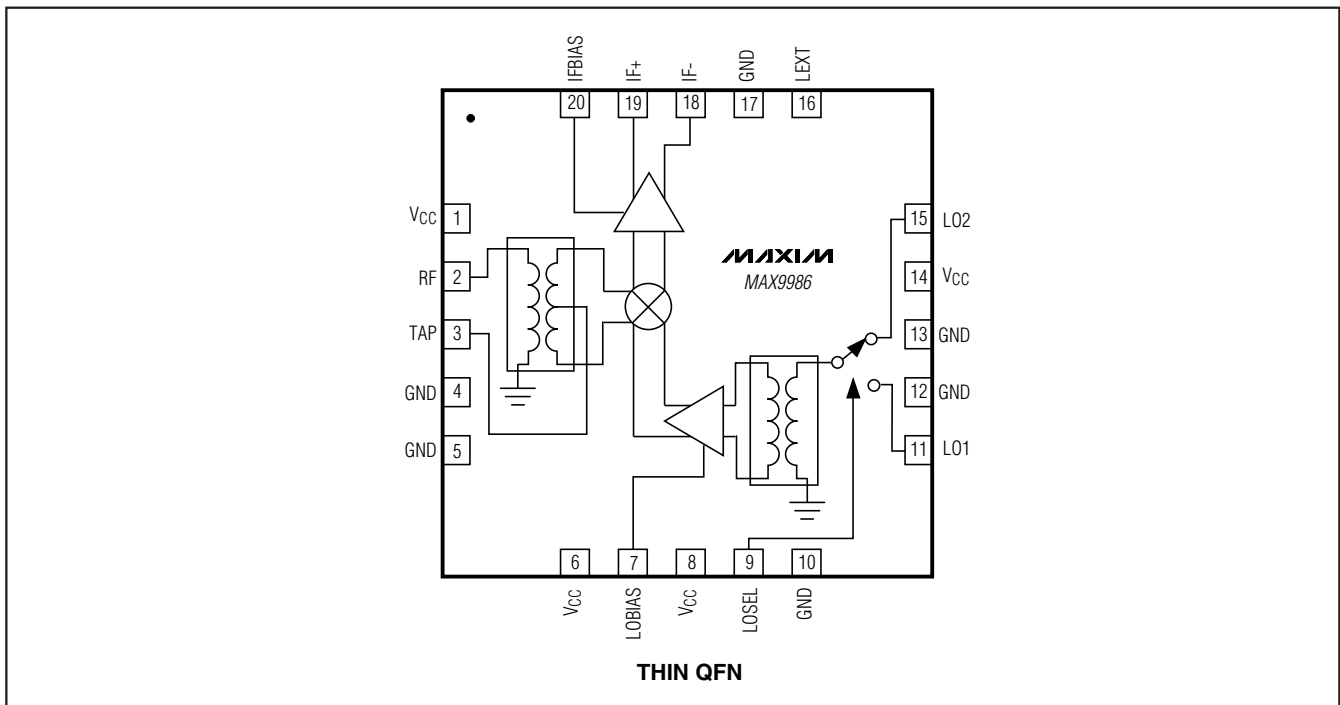
PROCESS: SiGe BiCMOS

SiGe High-Linearity, 815MHz to 995MHz Downconversion Mixer with LO Buffer/Switch

Table 1. Component List Referring to the Typical Application Circuit

COMPONENT	VALUE	DESCRIPTION
L1, L2	330nH	Wire-wound high-Q inductors (0805)
L3	30nH	Wire-wound high-Q inductor (0603)
C1	10pF	Microwave capacitor (0603)
C2, C4, C7, C8, C10, C11, C12	82pF	Microwave capacitors (0603)
C3, C5, C6, C9, C13, C14	0.01μF	Microwave capacitors (0603)
C15	220pF	Microwave capacitor (0402)
R1	953Ω	±1% resistor (0603)
R2	619Ω	±1% resistor (0603)
R3	3.57Ω	±1% resistor (1206)
T1	4:1 balun	IF balun
U1	MAX9986	Maxim IC

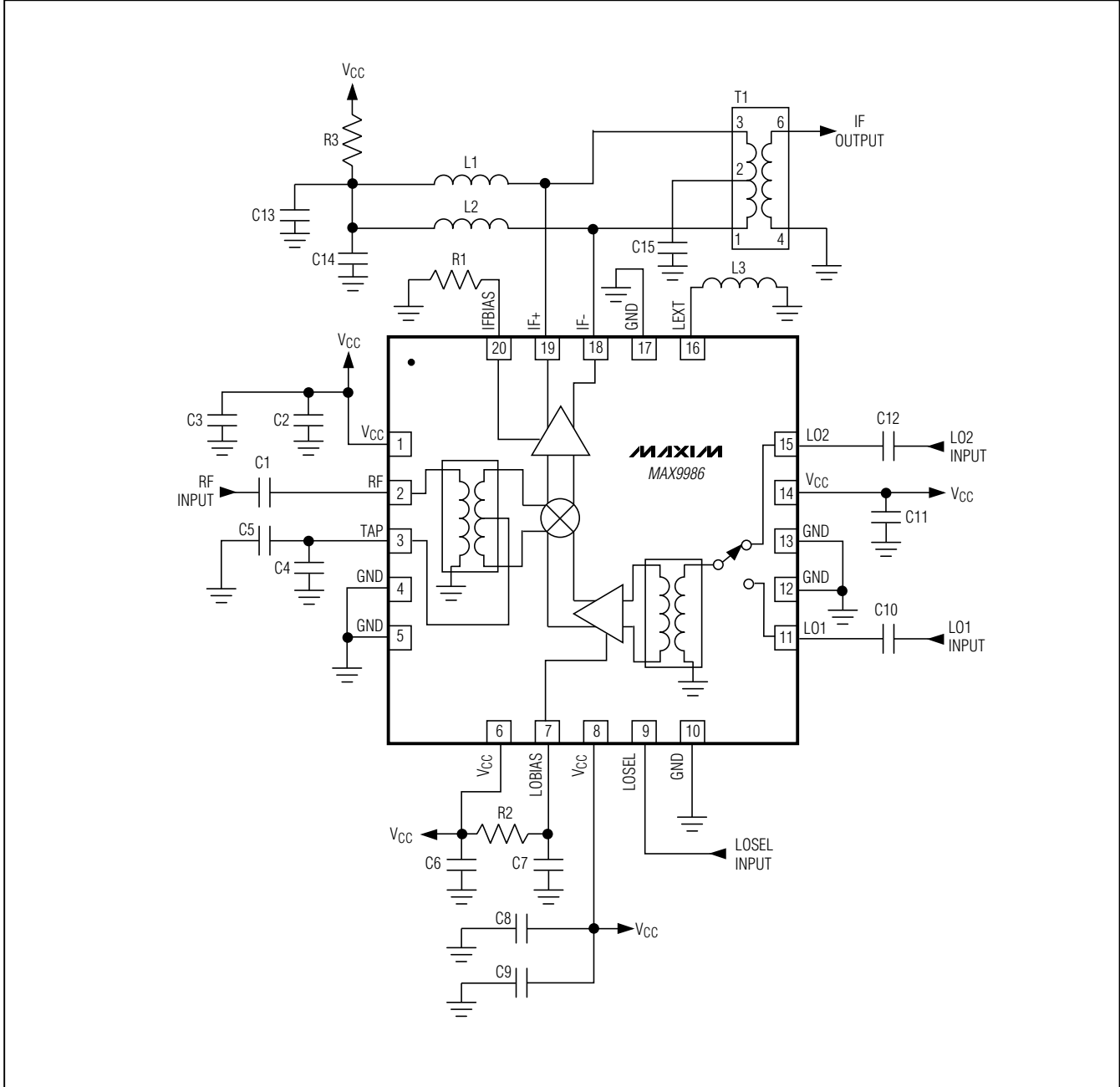
Pin Configuration/Functional Diagram



SiGe High-Linearity, 815MHz to 995MHz Downconversion Mixer with LO Buffer/Switch

Typical Application Circuit

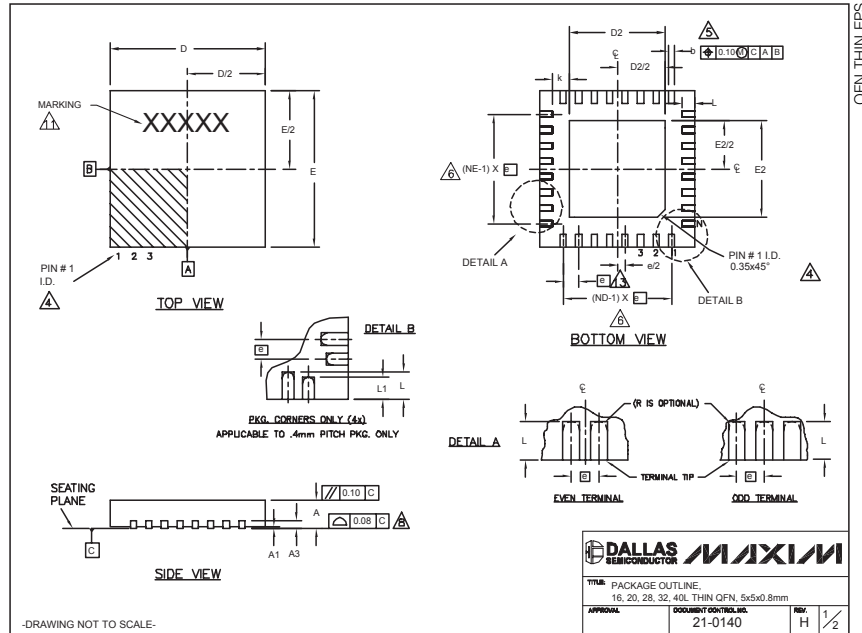
MAX9986



SiGe High-Linearity, 815MHz to 995MHz Downconversion Mixer with LO Buffer/Switch

Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to www.maxim-ic.com/packages.)



COMMON DIMENSIONS															
PKG. SYMBOL	16L 5x5			20L 5x5			28L 5x5			32L 5x5			40L 5x5		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.80
A1	0	0.02	0.05	0	0.02	0.05	0	0.02	0.05	0	0.02	0.05	0	0.02	0.05
A3	0.20 REF.			0.20 REF.			0.20 REF.			0.20 REF.			0.20 REF.		
b	0.25	0.30	0.35	0.25	0.30	0.35	0.20	0.25	0.30	0.20	0.25	0.30	0.15	0.20	0.25
D	4.90	5.00	5.10	4.90	5.00	5.10	4.90	5.00	5.10	4.90	5.00	5.10	4.90	5.00	5.10
E	4.90	5.00	5.10	4.90	5.00	5.10	4.90	5.00	5.10	4.90	5.00	5.10	4.90	5.00	5.10
e	0.80 BSC.			0.65 BSC.			0.50 BSC.			0.50 BSC.			0.40 BSC.		
k	0.25	-	-	0.25	-	-	0.25	-	-	0.25	-	-	0.25	0.35	0.45
L	0.30	0.40	0.50	0.45	0.55	0.65	0.45	0.55	0.65	0.30	0.40	0.50	0.40	0.50	0.60
L1	-	-	-	-	-	-	-	-	-	-	-	-	0.30	0.40	0.50
N	16			20			28			32			40		
ND	4			5			7			8			10		
NE	4			5			7			8			10		
JEDEC	WHHB			WHHC			WHHD-1			WHHD-2			---		

EXPOSED PAD VARIATIONS												
PKG. CODES	D2			E2			L	DOWN BONDS ALLOWED				
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.						
T1655-1	3.00	3.10	3.20	3.00	3.10	3.20	**	NO				
T1655-2	3.00	3.10	3.20	3.00	3.10	3.20	**	YES				
T1655N-1	3.00	3.10	3.20	3.00	3.10	3.20	**	NO				
T2055-2	3.00	3.10	3.20	3.00	3.10	3.20	**	NO				
T2055-3	3.00	3.10	3.20	3.00	3.10	3.20	**	YES				
T2055-4	3.00	3.10	3.20	3.00	3.10	3.20	**	NO				
T2055-5	3.15	3.25	3.35	3.15	3.25	3.35	0.40	YES				
T2855-1	3.15	3.25	3.35	3.15	3.25	3.35	**	NO				
T2855-2	2.60	2.70	2.80	2.60	2.70	2.80	**	NO				
T2855-3	3.15	3.25	3.35	3.15	3.25	3.35	**	YES				
T2855-4	2.60	2.70	2.80	2.60	2.70	2.80	**	YES				
T2855-5	2.60	2.70	2.80	2.60	2.70	2.80	**	NO				
T2855-6	3.15	3.25	3.35	3.15	3.25	3.35	**	NO				
T2855-7	2.60	2.70	2.80	2.60	2.70	2.80	**	YES				
T2855-8	3.15	3.25	3.35	3.15	3.25	3.35	0.40	YES				
T2855N-1	3.15	3.25	3.35	3.15	3.25	3.35	**	NO				
T3255-2	3.00	3.10	3.20	3.00	3.10	3.20	**	NO				
T3255-3	3.00	3.10	3.20	3.00	3.10	3.20	**	YES				
T3255-4	3.00	3.10	3.20	3.00	3.10	3.20	**	NO				
T3255N-1	3.00	3.10	3.20	3.00	3.10	3.20	**	NO				
T4055-1	3.20	3.30	3.40	3.20	3.30	3.40	**	YES				

** SEE COMMON DIMENSIONS TABLE

DALLAS SEMICONDUCTOR **MAXIM**

TITLE: PACKAGE OUTLINE
16, 20, 28, 32, 40L THIN GPN, 5x5x0.8mm

APPROVAL: DOCUMENT CONTROL NO. 21-0140 REV: H 2/2

-DRAWING NOT TO SCALE-

- NOTES:
- DIMENSIONING & TOLERANCING CONFORM TO ASME Y14.5M-1994.
 - ALL DIMENSIONS ARE IN MILLIMETERS, ANGLES ARE IN DEGREES.
 - N IS THE TOTAL NUMBER OF TERMINALS.
 - THE TERMINAL #1 IDENTIFIER AND TERMINAL NUMBERING CONVENTION SHALL CONFORM TO JEDEC 95-1 SPP-012. DETAILS OF TERMINAL #1 IDENTIFIER ARE OPTIONAL, BUT MUST BE LOCATED WITHIN THE ZONE INDICATED. THE TERMINAL #1 IDENTIFIER MAY BE EITHER A MOLD OR MARKED FEATURE.
 - DIMENSION b APPLIES TO METALLIZED TERMINAL AND IS MEASURED BETWEEN 0.25 mm AND 0.30 mm FROM TERMINAL TIP.
 - ND AND NE REFER TO THE NUMBER OF TERMINALS ON EACH D AND E SIDE RESPECTIVELY.
 - DEPOPULATION IS POSSIBLE IN A SYMMETRICAL FASHION.
 - COPLANARITY APPLIES TO THE EXPOSED HEAT SINK SLUG AS WELL AS THE TERMINALS.
 - DRAWING CONFORMS TO JEDEC MO220, EXCEPT EXPOSED PAD DIMENSION FOR T2855-1, T2855-3, AND T2855-6.
 - WARPAGE SHALL NOT EXCEED 0.10 mm.
 - MARKING IS FOR PACKAGE ORIENTATION REFERENCE ONLY.
 - NUMBER OF LEADS SHOWN ARE FOR REFERENCE ONLY.
 - LEAD CENTERLINES TO BE AT TRUE POSITION AS DEFINED BY BASIC DIMENSION "e", ±0.05.

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

12 **Maxim Integrated Products, 120 San Gabriel Drive, Sunnyvale, CA 94086 408-737-7600**



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- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
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- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.